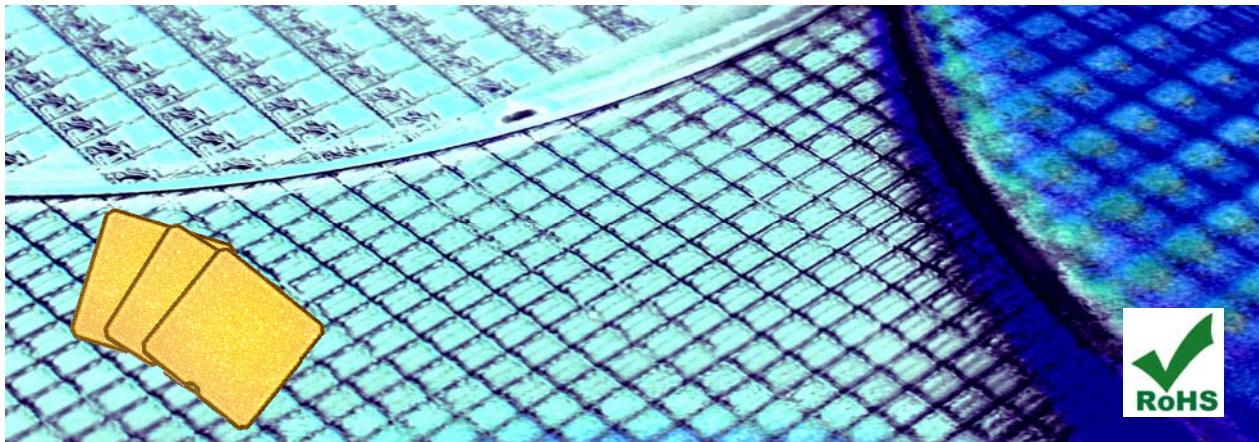


# UWSC – Ultra large-band Wire bonding Silicon Capacitor – Wire Bondable Vertical

Rev 1.5



## Key Features

- Ultra largeband performance up to 26 GHz
- Resonance free
- Phase stability
- Unique capacitance value of 1nF in 0101
- Ultra high stability of capacitance value
  - Temperature < ± 0.5% (-55°C to +150°C)
  - Voltage < 0.02 %/V
  - Negligible aging < 0.001%/1000 hours
- Ultra low ESR and ESL
- High reliability (FIT < 0.017 parts/billion hours)
- Compatible with standard wire bonding assembly (ball and wedge)\*

\* Please refer to our Assembly Application Note for more details

## Key Applications

- Optoelectronics/high-speed data
- Trans-Impedance Amplifiers (TIA)
- Receive-and-Transmit Optical Sub-Assembly (ROSA/TOSA)
- Synchronous Optical Networking (SONET)
- High speed digital logic
- Broadband test equipment
- Broadband microwave/millimeter wave
- Replacement of X7R and NP0
- Low profile applications (250 µm, 100 µm on request)

UWSC Capacitors target **optical communication systems** (ROSA/TOSA, SONET and all optoelectronics) as well as **high speed data systems** or products. The UWSC are designed for DC decoupling and bypass applications. The unique technology of integrated passive devices in silicon developed by IPDiA, offers **high rejection up to 26GHz**. The UWSC capacitors are manufactured with both deep trench and MOS semiconductor processes to cover low and high capacitance requirements.

The UWSC capacitors provide **very high reliability** and capacitance stability over temperature (±0.5%) and voltage. They have an extended operating temperature range from -55 to 150°C . **Reliable and repeatable performances** are obtained thanks to a fully controlled production line with high temperature curing (above 900°C) generating a highly pure oxide. These capacitors are compatible with standard wire bonding assembly (ball and wedge). They are RoHS-compliant and are available with thick gold terminations.

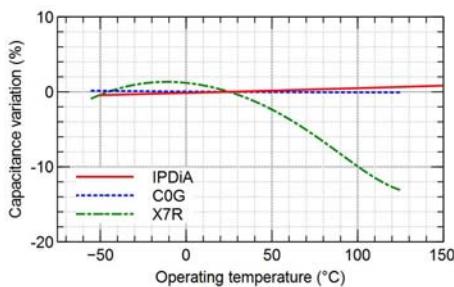
## Electrical Specifications

Part number	Product description	Case Size	Thickness
<b>UWSC.xxx</b>	Ultra largeband Wire bondable vertical Silicon Capacitor, from -55 to 150°C, 26GHz with Au termination		
935 153 622 410	Ultra largeband Wire bondable vertical Si Cap 1nF, BV>50V	0101	250µm
935 153 620 510	Ultra largeband Wire bondable vertical Si Cap 10nF, BV>50V	0303	250µm
935 153 624 522	Ultra largeband Wire bondable vertical Si Cap 22nF, BV>50V	0504	250µm
935 153 821 510	Ultra largeband Wire bondable vertical Si Cap 10nF, BV>30V	0202	250µm
935 154 622 410	Ultra largeband low profile Wire bondable vertical Si Cap 1 nF, BV>50V	0101	100µm
935 154 620 510	Ultra largeband low profile Wire bondable vertical Si Cap 10nF, BV>50V	0303	100µm
935 154 821 510	Ultra largeband low profile Wire bondable vertical Si Cap 10nF, BV>30V	0202	100µm

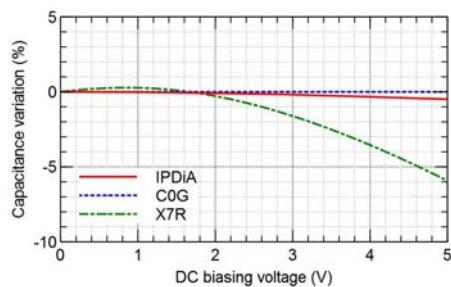
Parameters	Value
Capacitance range	10pF to 100 nF <sup>(*)</sup>
Capacitance tolerance	± 15 % <sup>(*)</sup>
Operating temperature range	-55 °C to 150 °C
Storage temperature	-70 °C to 165 °C
Temperature coefficient	<±0.5 %, from -55 °C to +150 °C
Breakdown voltage (BV)	11, 30, 50, 150, 450 V <sup>(*)</sup>
Capacitance variation versus RVDC	0.02 %/V (from 0 V to RVDC)
Equivalent Serial Inductance (ESL)	typ. 6 pH <sup>(**)</sup> @SRF
Equivalent Serial Resistance (ESR)	typ. 14 mΩ <sup>(**)</sup>
Insulation resistance	100 GΩ min @ RVDC & +25°C
Aging	Negligible, < 0.001 % / 1000h
Reliability	FIT<0.017 parts / billion hours.
Capacitor height	Max 250 µm or 100 µm

(\*\*) Other values on request

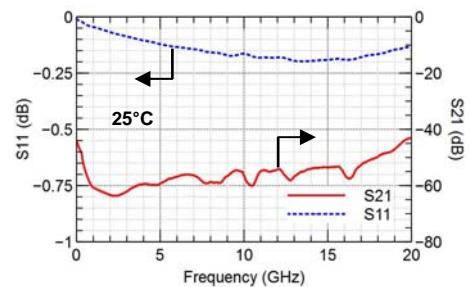
(\*\*\*) e.g. 10nF/0303/BV 50V



**Fig.1:** Capacitance variation vs temperature (for UWSC and MLCC technologies)

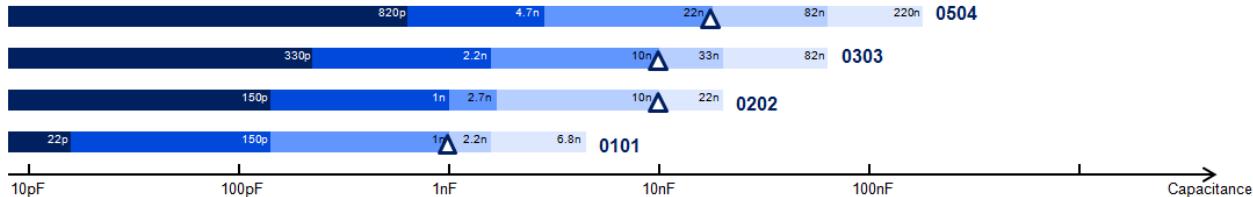


**Fig.2:** Capacitance variation vs DC biasing voltage (for UWSC and MLCC technologies)



**Fig.3:** 10 nF/0303 UWSC measurement results (S-parameters in shunt mode)

## UWSC Capacitance Range



△ Available parts – see table above  
For other values, contact your IPDiA sales representative

■ BV 450V ■ BV 50V ■ BV 11V  
■ BV 150V ■ BV 30V

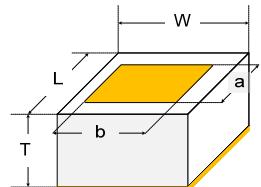
## Termination and Outline

### Termination

Can be directly mounted on the PCB using die bonding and wire bonding.  
Bottom electrode in Ti/Ni/Au and top electrode in Ti/Cu/Ni/Au. Other top finishings available on request (ex: 3µm Al/Si/Cu).  
Compatible with standard wire bonding assembly (ball and wedge).

### Package Outline

( mm )	Pad dimension		Case size (typ. ±0.01mm)		
	a	b	L	W	T
0101	>0.15	>0.15	0.25 <sup>(*)</sup>	0.25 <sup>(*)</sup>	
0201	>0.40	>0.15	0.50	0.25	
0202	>0.40	>0.40	0.50	0.50	
0303	>0.70	>0.70	0.80	0.80	
0404	>0.94	>0.94	1.04	1.04	
0503	>1.17	>0.72	1.27	0.82	0.25 (standard profile) or 0.10 (low profile)
0504	>1.28	>0.92	1.38	1.02	



## Packing

Tape and reel, waffle pack, film frame carrier or raw wafer delivery.

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ООО "ЛайфЭлектроникс"

"LifeElectronics" LLC

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

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- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
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- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
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Тел: +7 (812) 336 43 04 (многоканальный)  
Email: org@lifeelectronics.ru